

PACKAGE/ORDERING INFORMATION

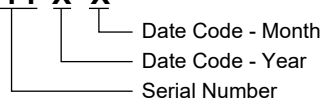
MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8045	SOT-23-5	-40°C to +85°C	SGM8045YN5G/TR	S25XX	Tape and Reel, 3000
	SOIC-8	-40°C to +85°C	SGM8045YS8G/TR	SGM8045YS8 XXXXX	Tape and Reel, 2500
	MSOP-8	-40°C to +85°C	SGM8045YMS8G/TR	SGM8045 YMS8 XXXXX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XX = Date Code. XXXXX = Date Code and Vendor Code.

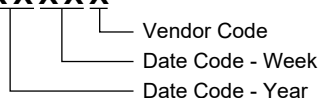
SOT-23-5

YYY X X



SOIC-8/MSOP-8

XXXXX



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage.....	6V
Analog Inputs (+IN, -IN).....	(-V _S) - 0.1V to (+V _S) + 0.1V
Differential Input Voltage.....	(-V _S) - (+V _S)
Junction Temperature.....	+150°C
Storage Temperature Range.....	-65°C to +150°C
Lead Temperature (Soldering, 10s).....	+260°C
ESD Susceptibility	
HBM.....	2000V
MM.....	400V

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range.....	-40°C to +85°C
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OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods

may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

ELECTRICAL CHARACTERISTICS

(At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V}$ to 5.0V , $-V_S = \text{GND}$, $A_V = 10$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$ ⁽¹⁾, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DC Electrical Characteristics						
Input Offset Voltage	V_{OS}	$V_{CM} = +V_S/2$		0.4	2.5	mV
Input Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$V_{CM} = +V_S/2$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		2.5		$\mu\text{V}/^\circ\text{C}$
Power Supply Rejection Ratio	PSRR	$+V_S = 1.4\text{V}$ to 5.5V	76	80		dB
Input Common Mode Voltage Range	V_{CMR}		$(-V_S) - 0.1$		$(+V_S) + 0.1$	V
Common Mode Rejection Ratio	CMRR	$+V_S = 5.0\text{V}$, $V_{CM} = -0.1\text{V}$ to 5.1V	68	84		dB
		$+V_S = 5.0\text{V}$, $V_{CM} = 2.5\text{V}$ to 5.1V	67	83		
		$+V_S = 5.0\text{V}$, $V_{CM} = -0.1\text{V}$ to 2.5V	63	78		
Large-Signal Voltage Gain	A_{VO}	$+V_S = 1.4\text{V}$, $R_L = 50\text{k}\Omega$, $V_{OUT} = (+V_S) - 0.1\text{V}$	70	80		dB
		$+V_S = 2.5\text{V}$, $R_L = 50\text{k}\Omega$, $V_{OUT} = (+V_S) - 0.1\text{V}$		88		
		$+V_S = 5.0\text{V}$, $R_L = 50\text{k}\Omega$, $V_{OUT} = (+V_S) - 0.1\text{V}$	80	93		
Input Bias Current	I_B			1		pA
Input Offset Current	I_{OS}			1		pA
Maximum Output Voltage Swing	V_{OH}	$+V_S = 1.4\text{V}$, $R_L = 50\text{k}\Omega$	1.390	1.395		V
		$+V_S = 2.5\text{V}$, $R_L = 50\text{k}\Omega$		2.497		
		$+V_S = 5.0\text{V}$, $R_L = 50\text{k}\Omega$	4.990	4.997		
	V_{OL}	$+V_S = 1.4\text{V}$, $R_L = 50\text{k}\Omega$		4.5	10	mV
		$+V_S = 2.5\text{V}$, $R_L = 50\text{k}\Omega$		3.0		
		$+V_S = 5.0\text{V}$, $R_L = 50\text{k}\Omega$		3.5	10	
Output Short-Circuit Current	I_{SC}	$+V_S = 2.5\text{V}$		5.5		mA
		$+V_S = 5.0\text{V}$	22	24		
Supply Voltage	V_{CC}		1.4		5.5	V
Quiescent Current	I_Q	$+V_S = 1.4\text{V}$		600		nA
		$+V_S = 2.5\text{V}$		660		
		$+V_S = 5.0\text{V}$		710	1500	

ELECTRICAL CHARACTERISTICS (continued)

(At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V}$ to 5.0V , $-V_S = \text{GND}$, $A_V = 10$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$, $C_L = 60\text{pF}$ ⁽¹⁾, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
AC Electrical Characteristics						
Gain-Bandwidth Product	GBP			100		kHz
Slew Rate	SR	$+V_S = 1.4\text{V}$, $V_{OUT} = 1\text{V}$ Step		13.5		V/ms
		$+V_S = 2.5\text{V}$, $V_{OUT} = 1\text{V}$ Step		15		
		$+V_S = 5.0\text{V}$, $V_{OUT} = 2\text{V}$ Step		16		
Phase Margin	PM	$+V_S = 1.4\text{V}$ to 5.5V		60		°
Input Voltage Noise	e_n p-p	$+V_S = 1.4\text{V}$, $f = 0.1\text{Hz}$ to 10Hz		3.6		μV_{P-P}
		$+V_S = 2.5\text{V}$, $f = 0.1\text{Hz}$ to 10Hz		3.2		
		$+V_S = 5.0\text{V}$, $f = 0.1\text{Hz}$ to 10Hz		3.2		
Input Voltage Noise Density	e_n	$+V_S = 1.4\text{V}$, $f = 1\text{kHz}$		170		$\text{nV}/\sqrt{\text{Hz}}$
		$+V_S = 2.5\text{V}$, $f = 1\text{kHz}$		160		
		$+V_S = 5.0\text{V}$, $f = 1\text{kHz}$		160		

NOTE: 1. Refer to Figure 1 and Figure 2.

TEST CIRCUITS

The test circuits used for the DC and AC tests are shown in Figure 1 and Figure 2. The bypass capacitors are laid out according to the rules discussed in "Supply Bypass".

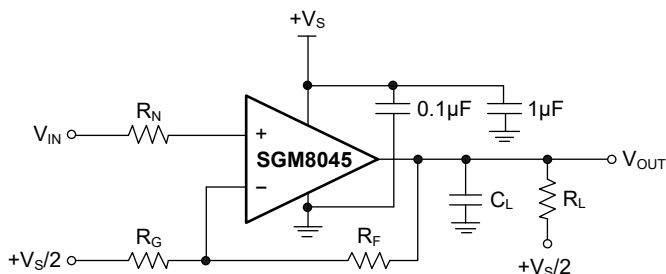


Figure 1. AC and DC Test Circuit for Most Non-Inverting Gain Conditions

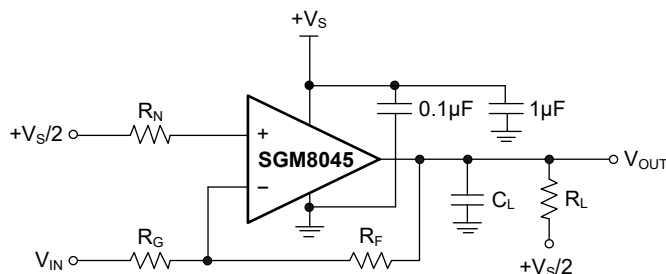
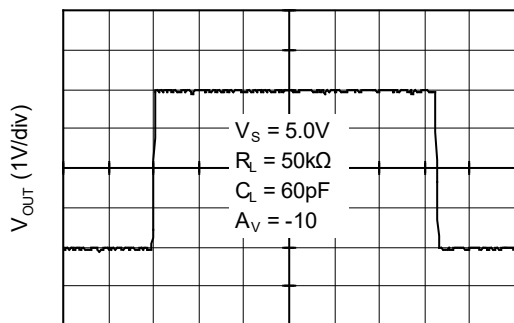


Figure 2. AC and DC Test Circuit for Most Inverting Gain Conditions

TYPICAL PERFORMANCE CHARACTERISTICS

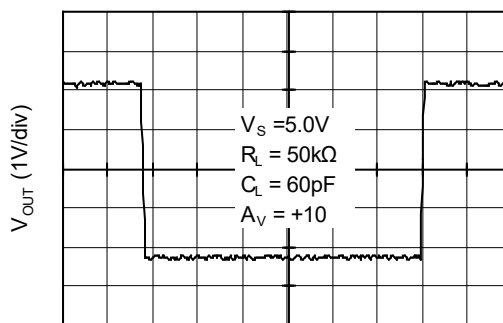
At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V}$ to 5.0V , $-V_S = \text{GND}$, $A_V = 10$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$, $C_L = 60\text{pF}$, unless otherwise noted.

Large Signal Inverting Pulse Response



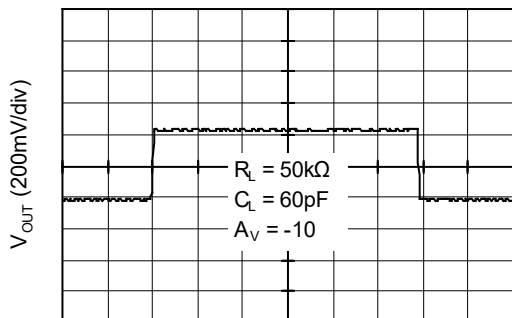
Time (5ms/div)

Large Signal Non-Inverting Pulse Response



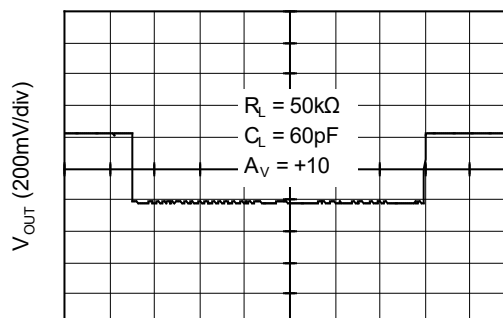
Time (5ms/div)

Small Signal Inverting Pulse Response



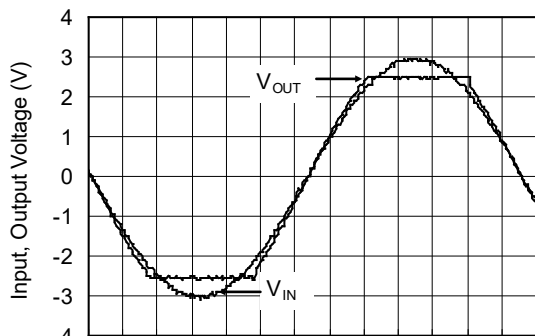
Time (5ms/div)

Small Signal Non-Inverting Pulse Response



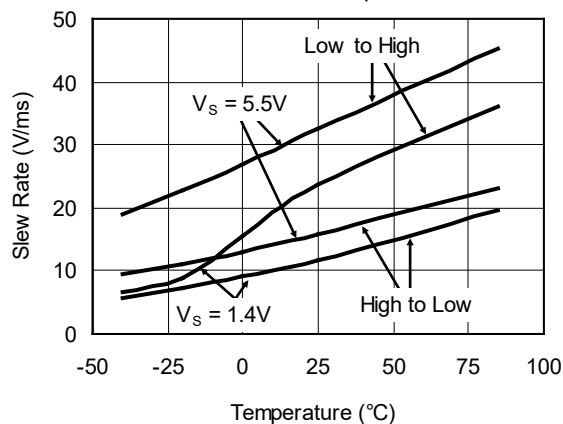
Time (5ms/div)

No Phase Reversal



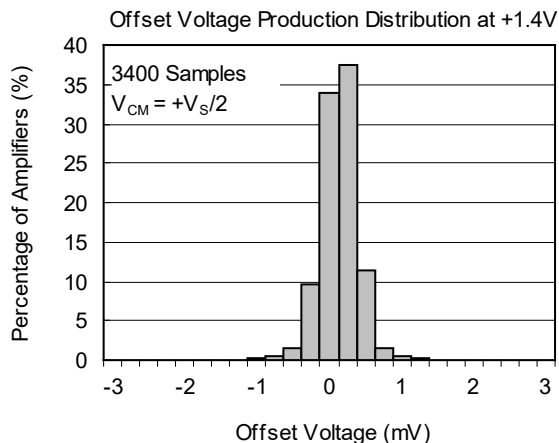
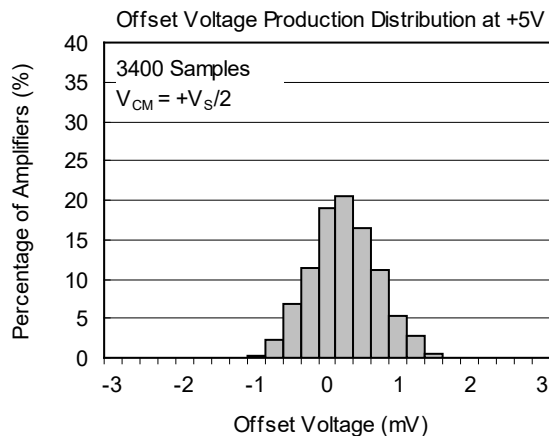
Time (5ms/div)

Slew Rate vs. Temperature



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V}$ to 5.0V , $-V_S = \text{GND}$, $A_V = 10$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$, $C_L = 60\text{pF}$, unless otherwise noted.

**REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

JANUARY 2013 – REV.A.1 to REV.A.2**Page**

Added Tape and Reel Information section 10~11

MAY 2011 – REV.A to REV.A.1**Page**

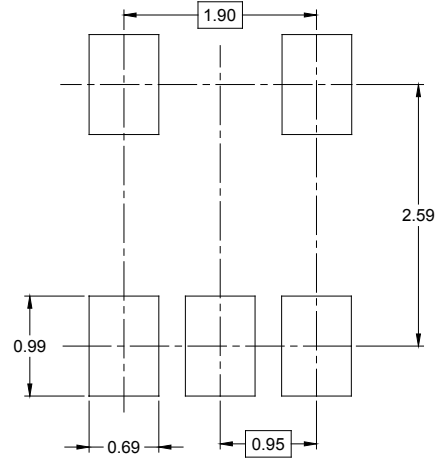
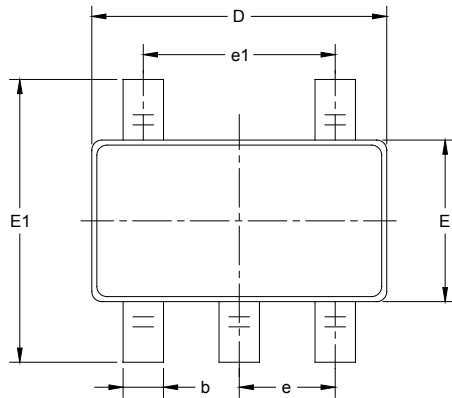
Updated Package Description All

Changes from Original (APRIL 2010) to REV.A**Page**

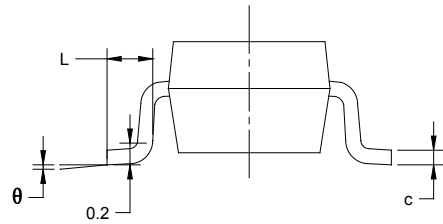
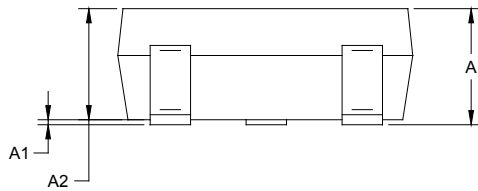
Changed from product preview to production data All

PACKAGE OUTLINE DIMENSIONS

SOT-23-5



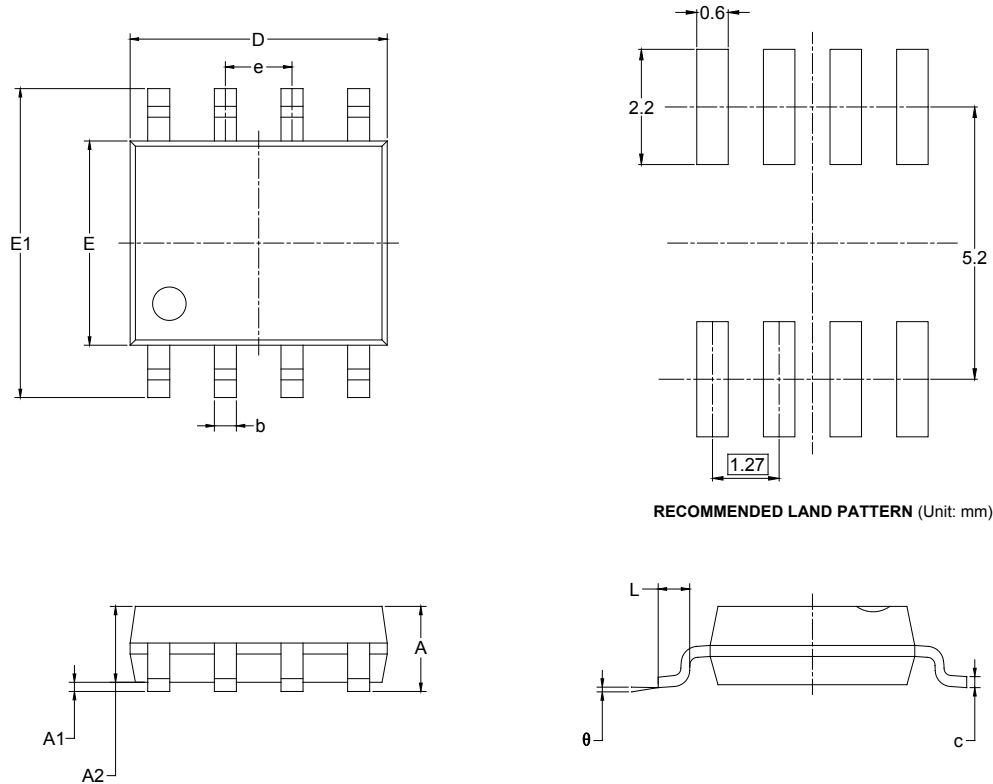
RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

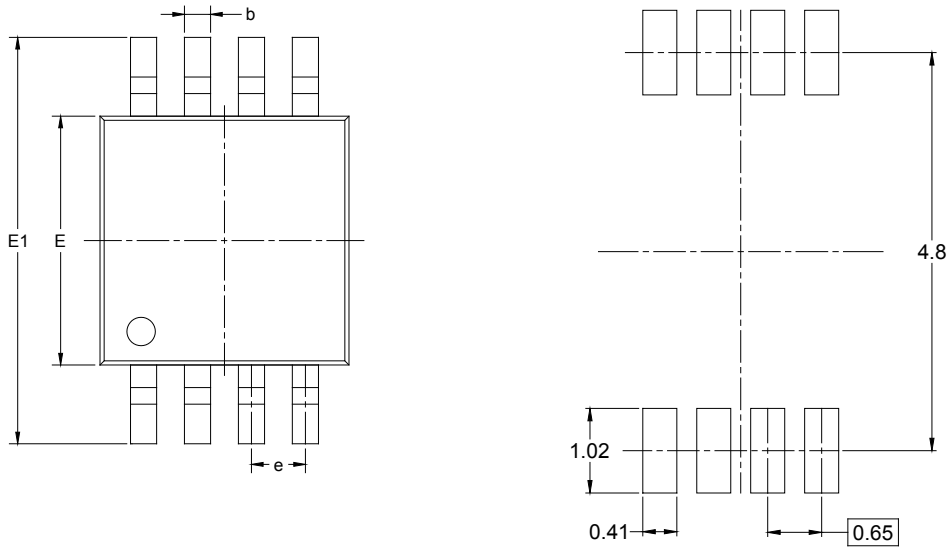
SOIC-8



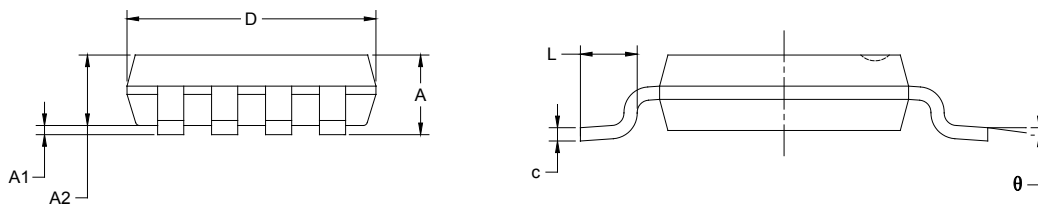
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

MSOP-8



RECOMMENDED LAND PATTERN (Unit: mm)

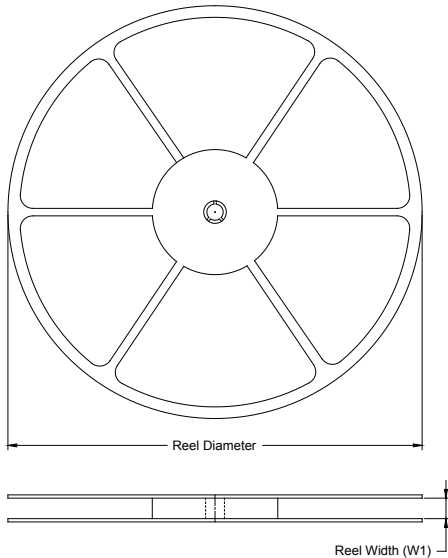


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
e	0.650 BSC		0.026 BSC	
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°

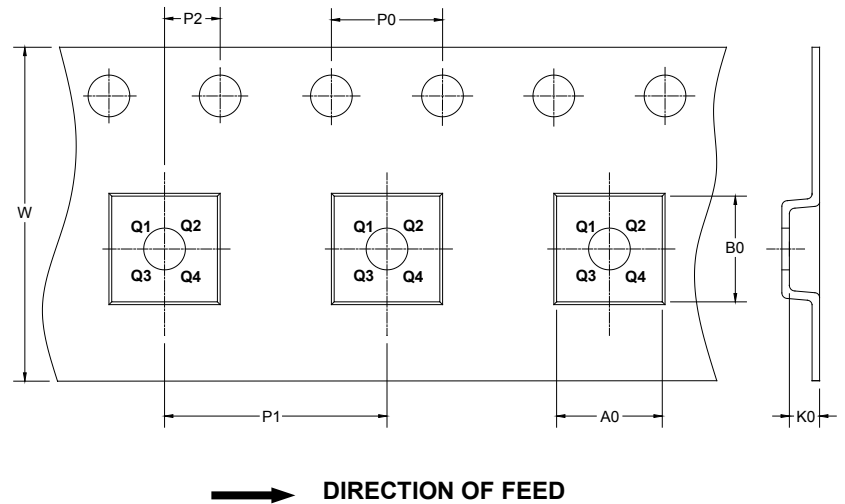
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

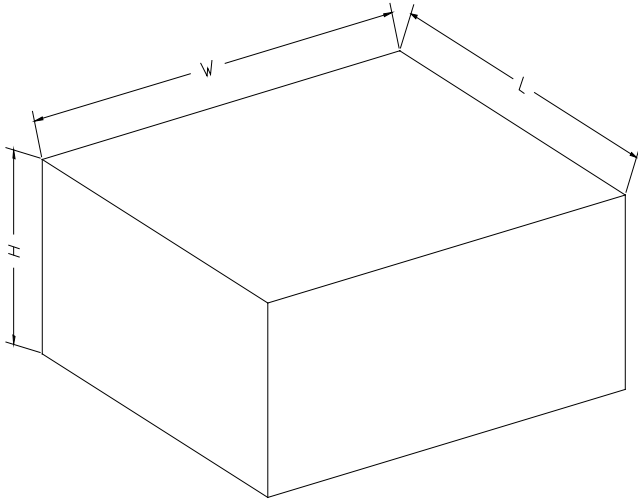
KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT-23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP-8	13"	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1

DD0001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5

DD00002